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BLF6G10-160RN; BLF6G10LS-160RN Power LDMOS transistor

Rev. 3 — 1 September 2015

AMPLEON Product data sheet

Product profile 1.

1.1 General description

160 W LDMOS power transistor for base station applications at frequencies from 700 MHz to 1000 MHz.

Table 1. **Typical performance**

Typical RF performance at T_{case} = 25 °C in a class-AB production test circuit.

| Mode of operation | f | V _{DS} | P _{L(AV)} | Gp | η_D | ACPR | |
|-------------------|------------|-----------------|--------------------|------|----------|----------------------|--|
| | (MHz) | (V) | (W) | (dB) | (%) | (dBc) | |
| 2-carrier W-CDMA | 920 to 960 | 32 | 32 | 22.5 | 27 | -41 <mark>[1]</mark> | |

[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF per carrier; carrier spacing 5 MHz.

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features

- Typical 2-carrier W-CDMA performance at frequencies of 920 MHz and 960 MHz, a supply voltage of 32 V and an I_{Dq} of 1200 mA:
 - Average output power = 32 W
 - Power gain = 22.5 dB
 - Efficiency = 27 %
 - ◆ ACPR = -41 dBc
- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (700 MHz to 1000 MHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding restriction of hazardous substances (RoHS)

1.3 Applications

RF power amplifiers for GSM, GSM EDGE, W-CDMA and CDMA base stations and multi carrier applications in the 700 MHz to 1000 MHz frequency range.

2. Pinning information

| Pin | Description | | Simplified outline | Graphic symbol |
|---------|--------------------|------------|--------------------|----------------|
| BLF6G10 | -160RN (SOT502A) | | | |
| 1 | drain | | | |
| 2 | gate | | | ۲ لـــــار |
| 3 | source | <u>[1]</u> | | |
| | | | | 3 |
| | | | | sym112 |
| BLF6G10 | LS-160RN (SOT502B) | | | |
| 1 | drain | | | |
| 2 | gate | | 3 | لــــا |
| 3 | source | <u>[1]</u> | | |
| | | | | 3 |
| | | | | sym112 |

3. Ordering information

Table 3.Ordering information

| ······································ | | | | | | |
|--|---------|---|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BLF6G10-160RN | - | flanged LDMOST ceramic package; 2 mounting holes; 2 leads | SOT502A | | | |
| BLF6G10LS-160RN | - | earless flanged LDMOST ceramic package; 2 leads | SOT502B | | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Мах | Unit |
|------------------|----------------------|------------|------|------|------|
| V _{DS} | drain-source voltage | | - | 65 | V |
| V _{GS} | gate-source voltage | | -0.5 | +13 | V |
| I _D | drain current | | - | 39 | А |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 225 | °C |

5. Thermal characteristics

| Table 5. | Thermal characteristics | | | | |
|-------------------------|-------------------------|----------------------------|-----------------|------|------|
| Symbol | Parameter | Conditions | Туре | Тур | Unit |
| R _{th(j-case)} | thermal resistance from | T _{case} = 80 °C; | BLF6G10-160RN | 0.5 | K/W |
| | junction to case | P _L = 32 W | BLF6G10LS-160RN | 0.44 | K/W |

6. Characteristics

Table 6. Characteristics

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|-----------------------------------|---|------|------|-----|------|
| V _{(BR)DSS} | drain-source breakdown voltage | V _{GS} = 0 V; I _D = 0.72 mA | 65 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | V_{DS} = 10 V; I _D = 216 mA | 1.4 | 1.9 | 2.4 | V |
| V_{GSq} | gate-source quiescent voltage | V _{DS} = 32 V; I _D = 1300 mA | 1.7 | 2.2 | 2.7 | V |
| I _{DSS} | drain leakage current | V_{GS} = 0 V; V_{DS} = 32 V | - | - | 5 | μA |
| I _{DSX} | drain cut-off current | $\label{eq:VGS} \begin{array}{l} V_{\mathrm{GS}} = V_{\mathrm{GS(th)}} + 3.75 \ V; \\ V_{\mathrm{DS}} = 10 \ V \end{array}$ | 30.6 | 39 | - | А |
| I _{GSS} | gate leakage current | V_{GS} = 13 V; V_{DS} = 0 V | - | - | 450 | nA |
| 9 _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 7.5 A | - | 13.5 | - | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 7.5 A$ | - | 0.07 | - | Ω |
| C _{rs} | feedback capacitance | V _{GS} = 0 V; V _{DS} = 32 V; f = 1 MHz | - | 4.2 | - | pF |

7. Application information

Table 7. Application information

Mode of operation: 2-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1-64 PDPCH; $f_1 = 922.5$ MHz; $f_2 = 927.5$ MHz; $f_3 = 952.5$ MHz; $f_4 = 957.5$ MHz; RF performance at $V_{DS} = 32$ V; $I_{Dq} = 1200$ mA; $T_{case} = 25$ °C; unless otherwise specified; in a class-AB production test circuit.

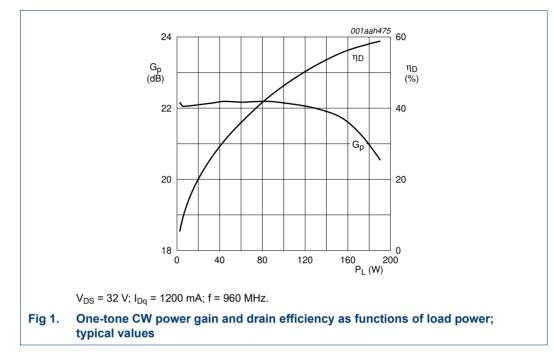
| Symbol | Parameter | Conditions | Min | Тур | Мах | Unit |
|------------------|------------------------------|---------------------------|-----|------|------|------|
| $P_{L(AV)}$ | average output power | | - | 32 | - | W |
| G _p | power gain | P _{L(AV)} = 32 W | 21 | 22.5 | - | dB |
| RL _{in} | input return loss | P _{L(AV)} = 32 W | - | -8 | -5.5 | dB |
| η _D | drain efficiency | P _{L(AV)} = 32 W | 25 | 27 | - | % |
| ACPR | adjacent channel power ratio | P _{L(AV)} = 32 W | - | -41 | -38 | dBc |

7.1 Ruggedness in class-AB operation

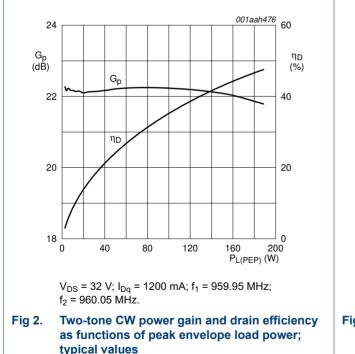
The BLF6G10-160RN and BLF6G10LS-160RN are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 1200 mA; P_L = 160 W (CW); f = 960 MHz.

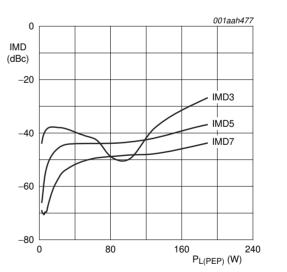
Power LDMOS transistor

7.2 One-tone CW



7.3 Two-tone CW





 V_{DS} = 32 V; I_{Dq} = 1200 mA; f_1 = 959.95 MHz; f_2 = 960.05 MHz.

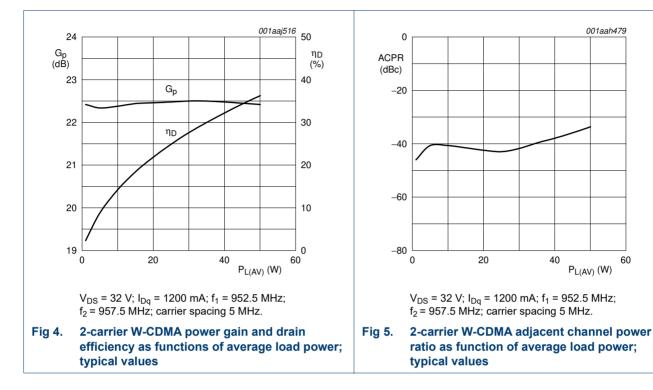
Fig 3. Intermodulation distortion as a function of peak envelope load power; typical values

Power LDMOS transistor

001aah479

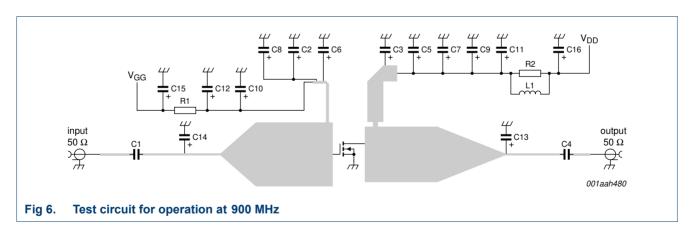
60

P_{L(AV)} (W)



7.4 2-carrier W-CDMA

Test information 8.



BLF6G10(LS)-160RN

Power LDMOS transistor

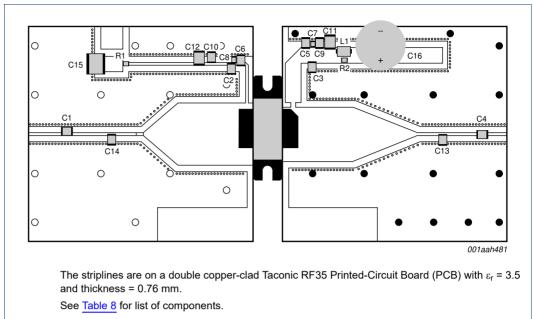


Fig 7. Component layout

Table 8. List of components (see Figure 6 and Figure 7) All capacitors should be soldered vertically.

| Component | Description | Value | Remarks |
|----------------|-----------------------------------|--------------|--|
| C1, C2, C3, C4 | multilayer ceramic chip capacitor | 68 pF | [1] |
| C5, C6 | multilayer ceramic chip capacitor | 560 pF | [1] |
| C7, C8 | multilayer ceramic chip capacitor | 330 nF; 50 V | [2] |
| C9, C10 | multilayer ceramic chip capacitor | 1.5 μF; 50 V | [2] |
| C11, C12 | multilayer ceramic chip capacitor | 4.5 μF; 50 V | [2] |
| C13 | multilayer ceramic chip capacitor | 2.20 pF | [1] |
| C14 | multilayer ceramic chip capacitor | 2.7 pF | [1] |
| C15 | SMD tantalum capacitor | 47 μF; 20 V | |
| C16 | electrolytic capacitor | 220 μF | |
| L1 | ferrite SMD bead | - | Ferroxcube BDS 3/3/8.9-4S2 or equivalent |
| R1 | SMD resistor | 4.7 Ω; 0.1 W | |
| R2 | SMD resistor | 6.8 Ω; 0.1 W | |

[1] American Technical Ceramics type 100B or capacitor of same quality.

[2] TDK or capacitor of same quality.

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Power LDMOS transistor

9. Package outline

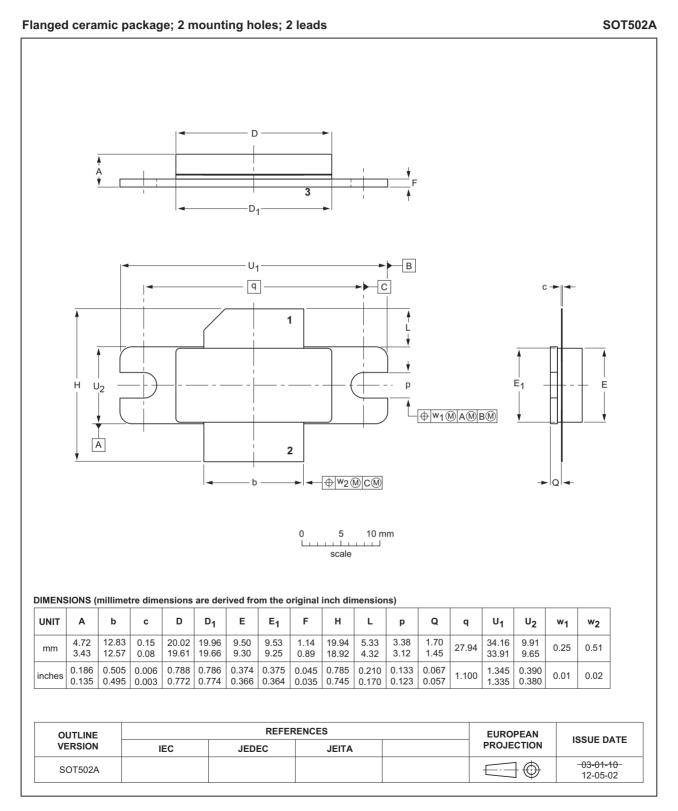


Fig 8. Package outline SOT502A

BLF6G10-160RN_10LS-160RN#3

BLF6G10(LS)-160RN

Power LDMOS transistor

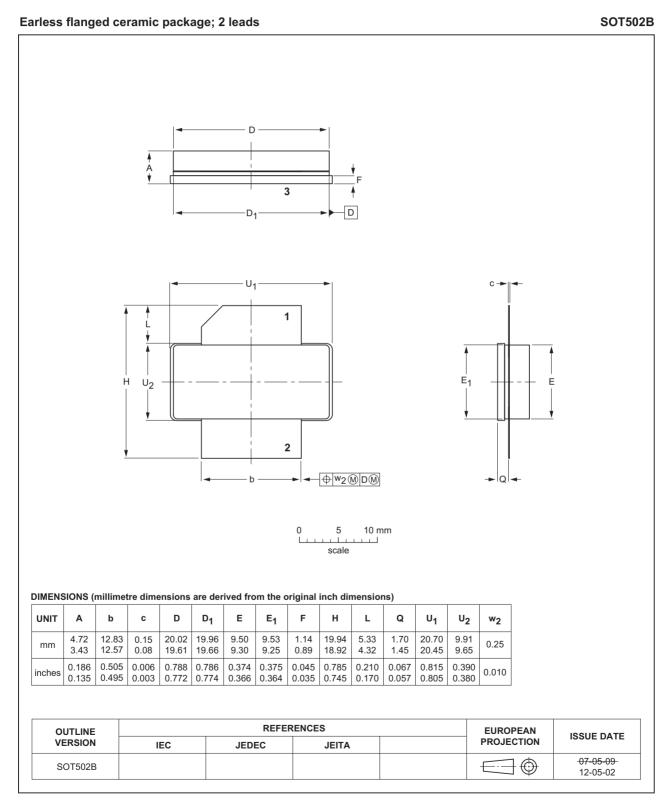


Fig 9. Package outline SOT502B

BLF6G10-160RN_10LS-160RN#3

10. Abbreviations

| Table 9. | Abbreviations |
|----------|---|
| Acronym | Description |
| 3GPP | Third Generation Partnership Project |
| CCDF | Complementary Cumulative Distribution Function |
| CDMA | Code Division Multiple Access |
| CW | Continuous Wave |
| DPCH | Dedicated Physical CHannel |
| EDGE | Enhanced Data rates for GSM Evolution |
| GSM | Global System for Mobile communications |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor |
| LDMOST | Laterally Diffused Metal-Oxide Semiconductor Transistor |
| PAR | Peak-to-Average power Ratio |
| PDPCH | transmission Power of the Dedicated Physical CHannel |
| RF | Radio Frequency |
| SMD | Surface Mounted Device |
| VSWR | Voltage Standing-Wave Ratio |
| W-CDMA | Wideband Code Division Multiple Access |

11. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | |
|----------------------------|---------------------------------|--|-----------------|------------------------------|--|
| BLF6G10-160RN_10LS-160RN#3 | 20150901 | Product data sheet | - | BLF6G10-160RN_10LS-160RN_2 | |
| Modifications: | | • The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. | | | |
| | Legal texts | s have been adapted | to the new comp | pany name where appropriate. | |
| BLF6G10-160RN_10LS-160RN_2 | 20100121 | Product data sheet | - | BLF6G10-160RN_10LS-160RN_1 | |
| BLF6G10-160RN_10LS-160RN_1 | 20090120 | Product data sheet | - | - | |

12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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